



BUK9Y1R9-40H

N-channel 40 V, 1.9 mΩ logic level MOSFET in LPAK56

10 January 2025

Product data sheet

1. General description

Automotive qualified N-channel MOSFET using the latest Trench 9 low ohmic superjunction technology, housed in a robust LPAK56 package. This product has been fully designed and qualified to meet AEC-Q101 requirements delivering high performance and endurance.

2. Features and benefits

- Fully automotive qualified to AEC-Q101:
 - 175 °C rating suitable for thermally demanding environments
- Trench 9 Superjunction technology:
 - Reduced cell pitch enables enhanced power density and efficiency with lower R_{DSon} in same footprint
 - Improved SOA and avalanche capability compared to standard TrenchMOS
 - Tight $V_{GS(th)}$ limits enable easy paralleling of MOSFETs
- LPAK Gull Wing leads:
 - High Board Level Reliability absorbing mechanical stress during thermal cycling, unlike traditional QFN packages
 - Visual (AOI) soldering inspection, no need for expensive x-ray equipment
 - Easy solder wetting for good mechanical solder joint
- LPAK copper clip technology:
 - Improved reliability, with reduced R_{th} and R_{DSon}
 - Increases maximum current capability and improved current spreading

3. Applications

- 12 V automotive systems
- Motors, lamps and solenoid control
- Start-Stop micro-hybrid applications
- Transmission control
- Ultra high performance power switching

4. Quick reference data

Table 1. Quick reference data

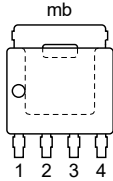
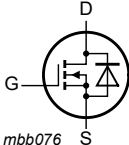
| Symbol | Parameter | Conditions | | Min | Typ | Max | Unit |
|-------------------------------|----------------------------------|---|-----|-----|------|-----|------|
| V_{DS} | drain-source voltage | $25\text{ °C} \leq T_j \leq 175\text{ °C}$ | | - | - | 40 | V |
| I_D | drain current | $V_{GS} = 10\text{ V}; T_{mb} = 25\text{ °C}$ | [1] | - | - | 120 | A |
| P_{tot} | total power dissipation | $T_{mb} = 25\text{ °C}; \text{Fig. 1}$ | | - | - | 217 | W |
| Static characteristics | | | | | | | |
| R_{DSon} | drain-source on-state resistance | $V_{GS} = 10\text{ V}; I_D = 25\text{ A}; T_j = 25\text{ °C}; \text{Fig. 10}$ | | 1 | 1.44 | 1.9 | mΩ |

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|-------------------------|-------------------|--|-----|------|------|------|
| Dynamic characteristics | | | | | | |
| Q _{GD} | gate-drain charge | I _D = 25 A; V _{DS} = 20 V; V _{GS} = 4.5 V; Fig. 12 ; Fig. 13 | - | 7.3 | 14.6 | nC |
| Source-drain diode | | | | | | |
| Q _r | recovered charge | I _S = 25 A; dI _S /dt = -100 A/μs; V _{GS} = 0 V; | - | 26.8 | - | nC |
| S | softness factor | V _{DS} = 20 V; T _j = 25 °C | - | 0.85 | - | |

[1] 120A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature

5. Pinning information

Table 2. Pinning information

| Pin | Symbol | Description | Simplified outline | Graphic symbol |
|-----|--------|-----------------------------------|--|---|
| 1 | S | source |  LPAK56; Power-SO8 (SOT669) |  mbb076 |
| 2 | S | source | | |
| 3 | S | source | | |
| 4 | G | gate | | |
| mb | D | mounting base; connected to drain | | |

6. Ordering information

Table 3. Ordering information

| Type number | Package | | |
|------------------------------|-------------------|--|------------------------|
| | Name | Description | Version |
| BUK9Y1R9-40H | LPAK56; Power-SO8 | plastic, single-ended surface-mounted package; 4 terminals | SOT669 |

7. Marking

Table 4. Marking codes

| Type number | Marking code |
|--------------|--------------|
| BUK9Y1R9-40H | 91H940 |

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). T_j = 25 °C unless otherwise stated.

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|-------------------------|---|---------|-----|------|
| V _{DS} | drain-source voltage | 25 °C ≤ T _j ≤ 175 °C | - | 40 | V |
| V _{GS} | gate-source voltage | | [1] -20 | 20 | V |
| P _{tot} | total power dissipation | T _{mb} = 25 °C; Fig. 1 | - | 217 | W |
| I _D | drain current | V _{GS} = 10 V; T _{mb} = 25 °C | [2] - | 120 | A |
| I _{DM} | peak drain current | pulsed; t _p ≤ 10 μs; T _{mb} = 25 °C; Fig. 2 | - | 600 | A |
| T _{stg} | storage temperature | | -55 | 175 | °C |

| Symbol | Parameter | Conditions | | Min | Max | Unit |
|----------------------|--|--|---------|-----|-----|------|
| T _j | junction temperature | | | -55 | 175 | °C |
| Source-drain diode | | | | | | |
| I _S | source current | T _{mb} = 25 °C | [2] | - | 120 | A |
| I _{SM} | peak source current | pulsed; t _p ≤ 10 μs; T _{mb} = 25 °C | | - | 600 | A |
| Avalanche ruggedness | | | | | | |
| E _{DS(AL)S} | non-repetitive drain-source avalanche energy | I _D = 120 A; V _{sup} ≤ 40 V; R _{GS} = 50 Ω; V _{GS} = 10 V; T _{j(init)} = 25 °C; unclamped; Fig. 3 | [3] [4] | - | 108 | mJ |

- [1] Refer to application note AN90001 for further information.
- [2] 120A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature
- [3] Single-pulse avalanche rating limited by maximum junction temperature of 175 °C
- [4] Refer to application note AN10273 for further information

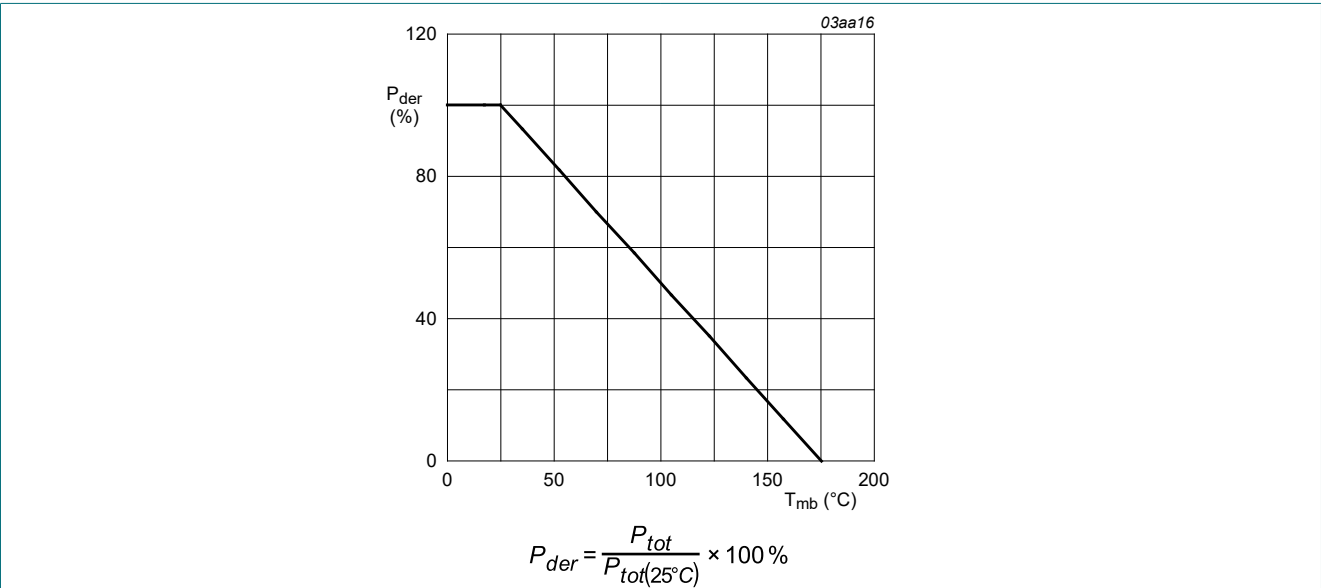


Fig. 1. Normalized total power dissipation as a function of mounting base temperature

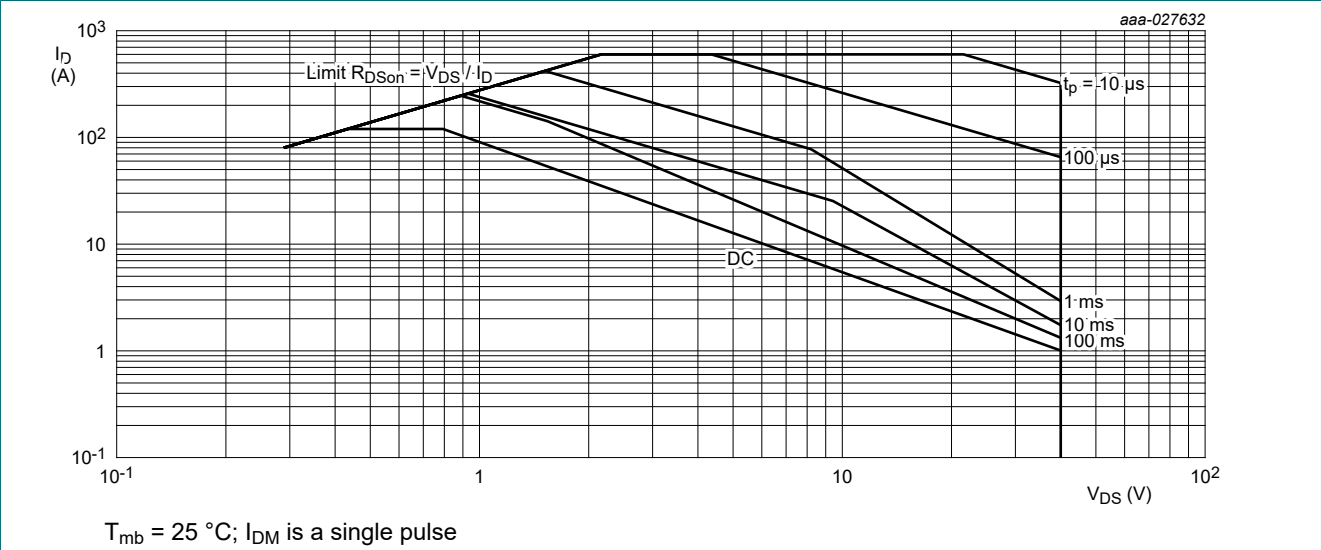
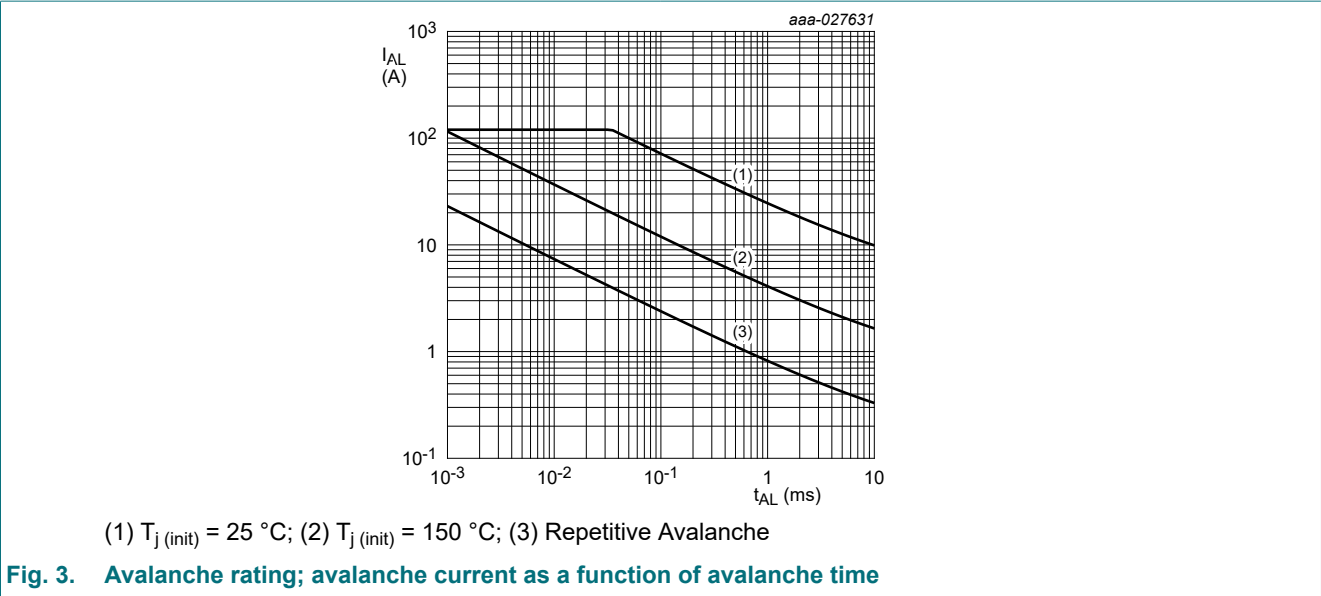


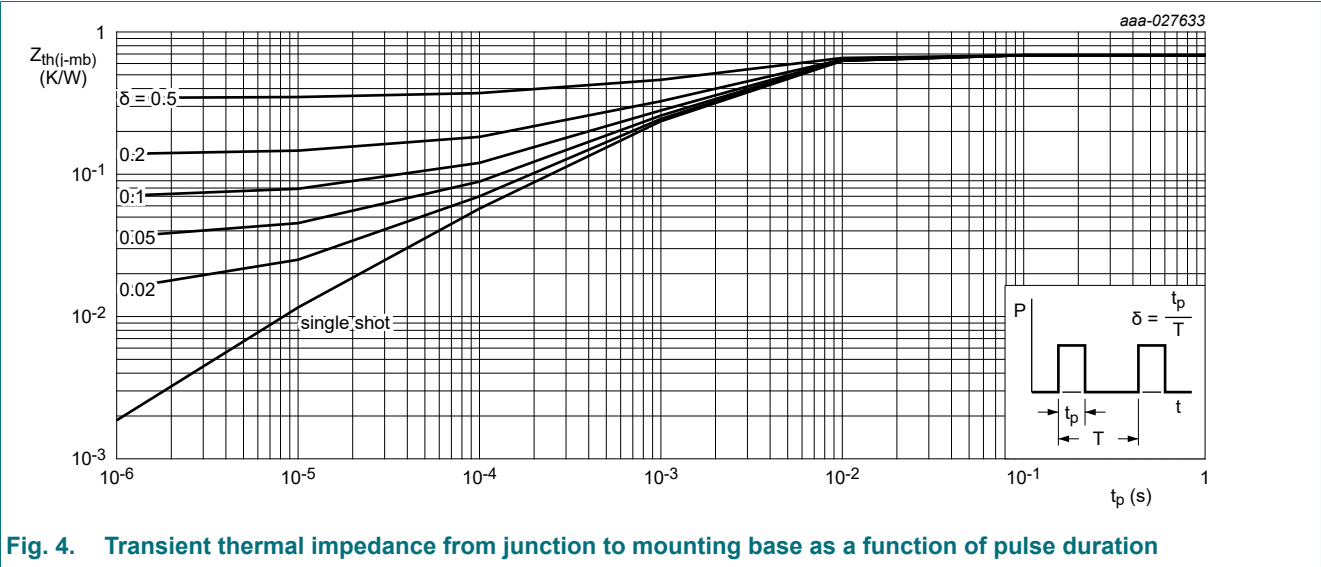
Fig. 2. Safe operating area; continuous and peak drain currents as a function of drain-source voltage



9. Thermal characteristics

Table 6. Thermal characteristics

| Symbol | Parameter | Conditions | | Min | Typ | Max | Unit |
|----------------|---|------------|--|-----|-----|------|------|
| $R_{th(j-mb)}$ | thermal resistance from junction to mounting base | Fig. 4 | | - | 0.5 | 0.69 | K/W |

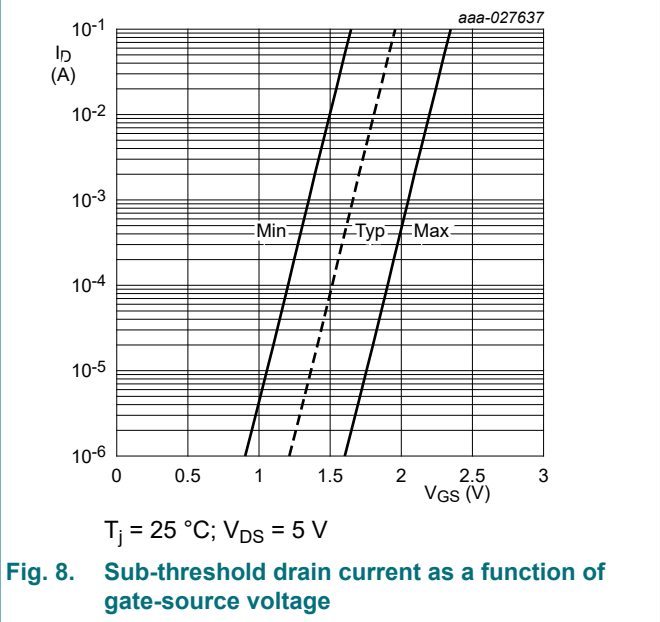
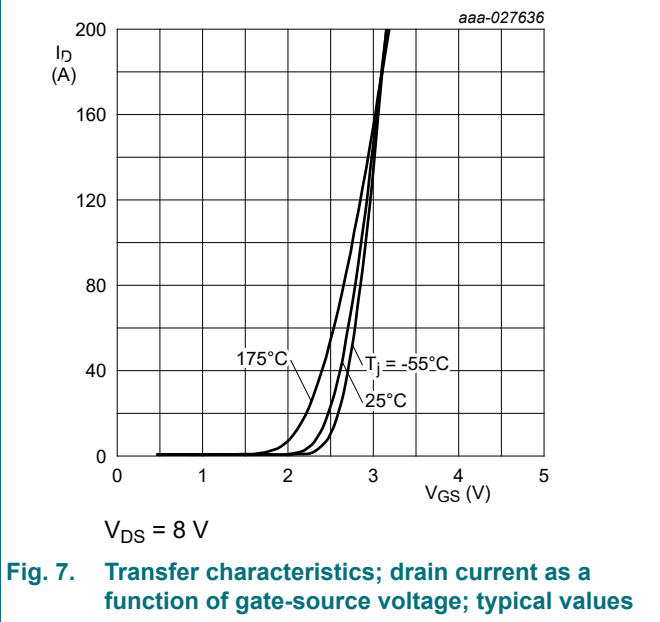
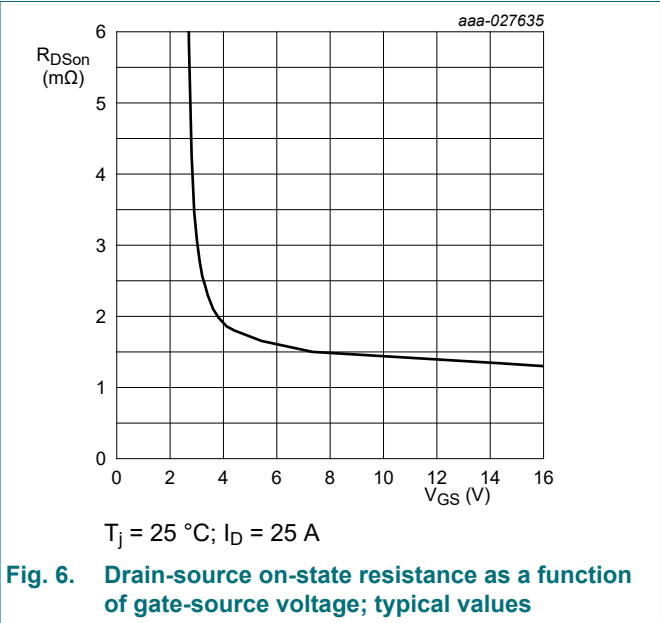
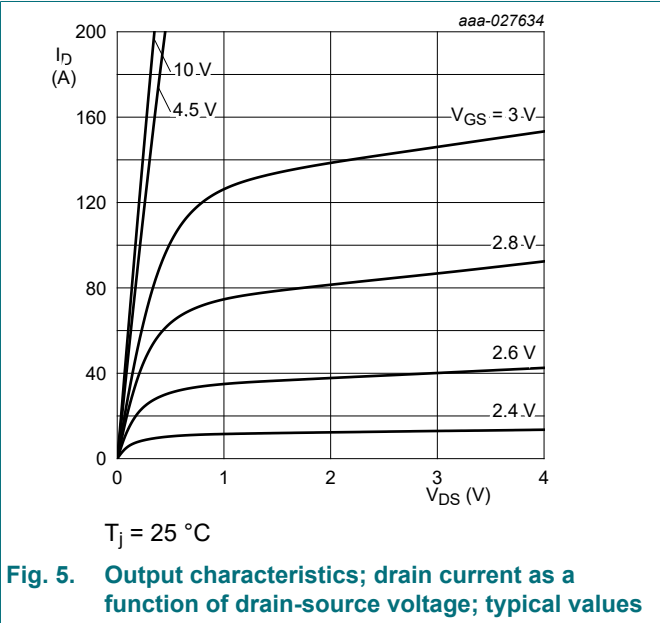


10. Characteristics

Table 7. Characteristics

| Symbol | Parameter | Conditions | | Min | Typ | Max | Unit |
|-------------------------|----------------------------------|---|--|------|------|------|------|
| Static characteristics | | | | | | | |
| V _{(BR)DSS} | drain-source breakdown voltage | I _D = 250 μA; V _{GS} = 0 V; T _J = 25 °C | | 40 | 43 | - | V |
| | | I _D = 250 μA; V _{GS} = 0 V; T _J = -40 °C | | - | 40.5 | - | V |
| | | I _D = 250 μA; V _{GS} = 0 V; T _J = -55 °C | | 36 | 40 | - | V |
| V _{GS(th)} | gate-source threshold voltage | I _D = 1 mA; V _{DS} =V _{GS} ; T _J = 25 °C; Fig. 8 ; Fig. 9 | | 1.35 | 1.66 | 2.05 | V |
| | | I _D = 1 mA; V _{DS} =V _{GS} ; T _J = 175 °C; Fig. 9 | | 0.6 | - | - | V |
| | | I _D = 1 mA; V _{DS} =V _{GS} ; T _J = -55 °C; Fig. 9 | | - | - | 2.5 | V |
| I _{DSS} | drain leakage current | V _{DS} = 40 V; V _{GS} = 0 V; T _J = 25 °C | | - | 0.13 | 5 | μA |
| | | V _{DS} = 16 V; V _{GS} = 0 V; T _J = 125 °C | | - | 1.5 | 10 | μA |
| | | V _{DS} = 40 V; V _{GS} = 0 V; T _J = 175 °C | | - | 194 | 500 | μA |
| I _{GSS} | gate leakage current | V _{GS} = 16 V; V _{DS} = 0 V; T _J = 25 °C | | - | 2 | 100 | nA |
| | | V _{GS} = -16 V; V _{DS} = 0 V; T _J = 25 °C | | - | 2 | 100 | nA |
| R _{DSon} | drain-source on-state resistance | V _{GS} = 10 V; I _D = 25 A; T _J = 25 °C; Fig. 10 | | 1 | 1.44 | 1.9 | mΩ |
| | | V _{GS} = 10 V; I _D = 25 A; T _J = 105 °C; Fig. 11 | | 1.5 | 2.2 | 3 | mΩ |
| | | V _{GS} = 10 V; I _D = 25 A; T _J = 125 °C; Fig. 11 | | 1.65 | 2.43 | 3.3 | mΩ |
| | | V _{GS} = 10 V; I _D = 25 A; T _J = 175 °C; Fig. 11 | | 2.1 | 3.06 | 4.2 | mΩ |
| | | V _{GS} = 4.5 V; I _D = 25 A; T _J = 25 °C; Fig. 10 | | 1.3 | 1.85 | 2.6 | mΩ |
| | | V _{GS} = 4.5 V; I _D = 25 A; T _J = 105 °C; Fig. 11 | | 1.9 | 2.8 | 4.1 | mΩ |
| | | V _{GS} = 4.5 V; I _D = 25 A; T _J = 125 °C; Fig. 11 | | 2.1 | 3.1 | 4.5 | mΩ |
| | | V _{GS} = 4.5 V; I _D = 25 A; T _J = 175 °C; Fig. 11 | | 2.7 | 3.9 | 5.7 | mΩ |
| R _G | gate resistance | f = 1 MHz; T _J = 25 °C | | 0.32 | 0.8 | 2 | Ω |
| Dynamic characteristics | | | | | | | |
| Q _{G(tot)} | total gate charge | I _D = 25 A; V _{DS} = 20 V; V _{GS} = 10 V; Fig. 12 ; Fig. 13 | | - | 66.4 | 93 | nC |
| | | I _D = 25 A; V _{DS} = 20 V; V _{GS} = 4.5 V; Fig. 12 ; Fig. 13 | | - | 30.4 | 42.7 | nC |
| Q _{GS} | gate-source charge | | | - | 11 | 16.5 | nC |
| Q _{GD} | gate-drain charge | | | - | 7.3 | 14.6 | nC |
| C _{iss} | input capacitance | V _{DS} = 25 V; V _{GS} = 0 V; f = 1 MHz; T _J = 25 °C; Fig. 14 | | - | 4665 | 6531 | pF |
| C _{oss} | output capacitance | | | - | 960 | 1340 | pF |
| C _{rss} | reverse transfer capacitance | | | - | 180 | 392 | pF |
| t _{d(on)} | turn-on delay time | V _{DS} = 20 V; R _L = 0.8 Ω; V _{GS} = 4.5 V; R _{G(ext)} = 5 Ω | | - | 26.5 | - | ns |
| t _r | rise time | | | - | 30.6 | - | ns |
| t _{d(off)} | turn-off delay time | | | - | 33.5 | - | ns |
| t _f | fall time | | | - | 20.5 | - | ns |

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|--------------------|-----------------------|---|-----|------|-----|------|
| Source-drain diode | | | | | | |
| V_{SD} | source-drain voltage | $I_S = 25\text{ A}$; $V_{GS} = 0\text{ V}$; $T_J = 25\text{ °C}$; Fig. 15 | - | 0.8 | 1.2 | V |
| t_{rr} | reverse recovery time | $I_S = 25\text{ A}$; $dI_S/dt = -100\text{ A/}\mu\text{s}$; $V_{GS} = 0\text{ V}$; | - | 32.3 | - | ns |
| Q_r | recovered charge | $V_{DS} = 20\text{ V}$; $T_J = 25\text{ °C}$ | - | 26.8 | - | nC |
| S | softness factor | | - | 0.85 | - | |
| | | $I_S = 25\text{ A}$; $dI_S/dt = -500\text{ A/}\mu\text{s}$; $V_{GS} = 0\text{ V}$; | - | 0.7 | - | |
| | | $V_{DS} = 20\text{ V}$; $T_J = 25\text{ °C}$ | | | | |



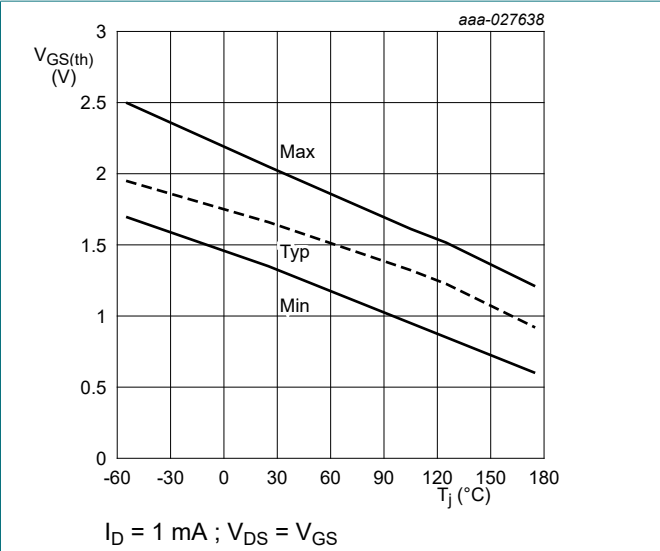


Fig. 9. Gate-source threshold voltage as a function of junction temperature

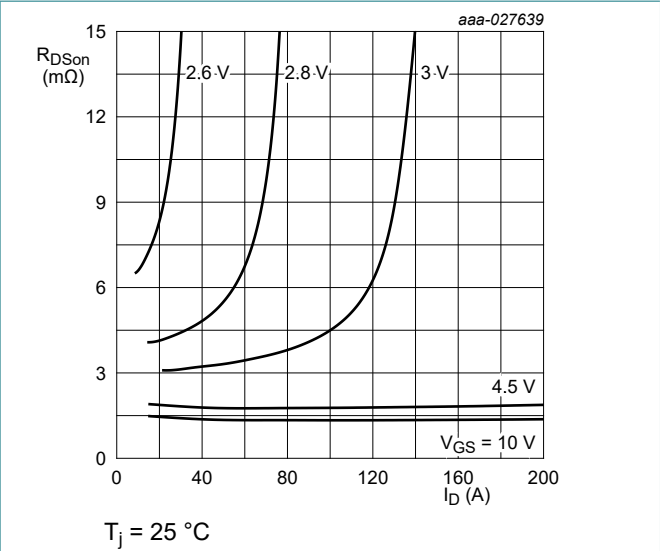


Fig. 10. Drain-source on-state resistance as a function of drain current; typical values

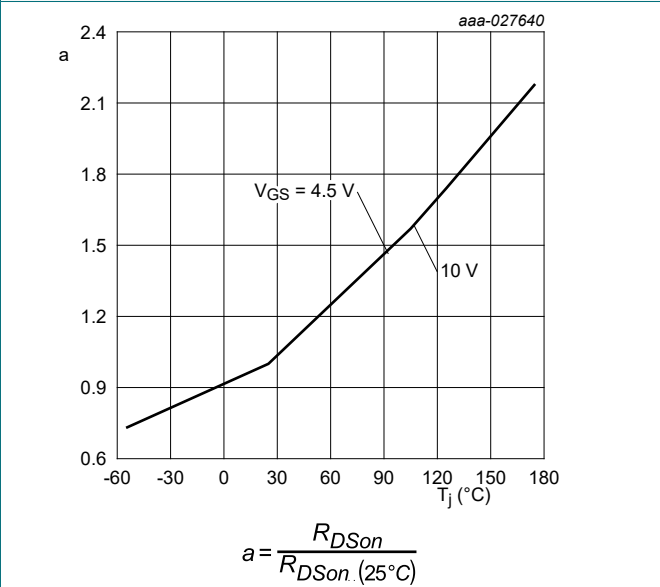


Fig. 11. Normalized drain-source on-state resistance factor as a function of junction temperature

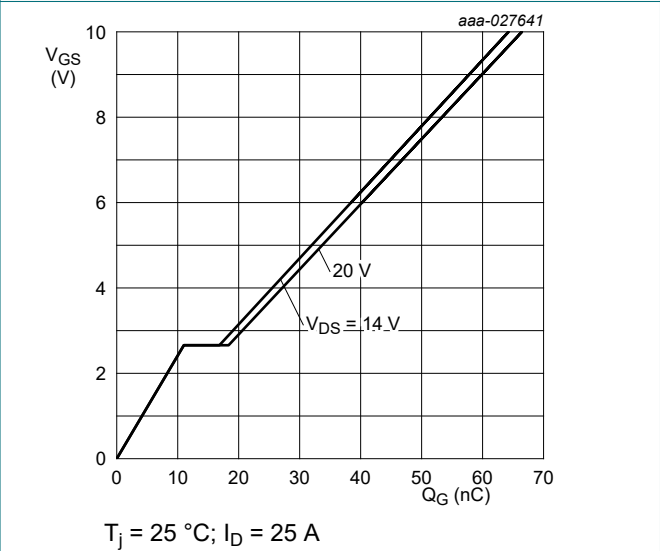


Fig. 12. Gate-source voltage as a function of gate charge; typical values

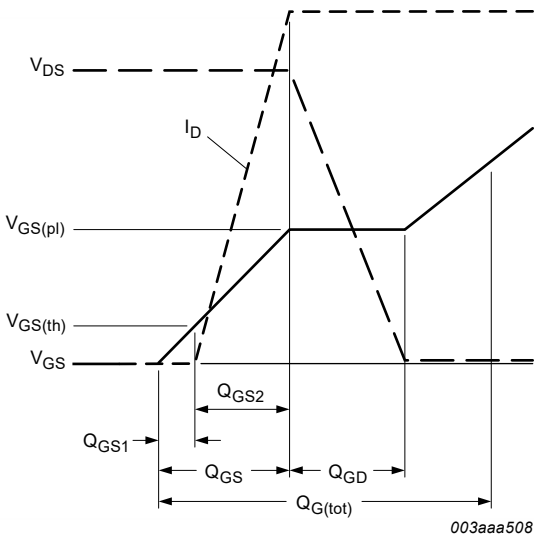


Fig. 13. Gate charge waveform definitions

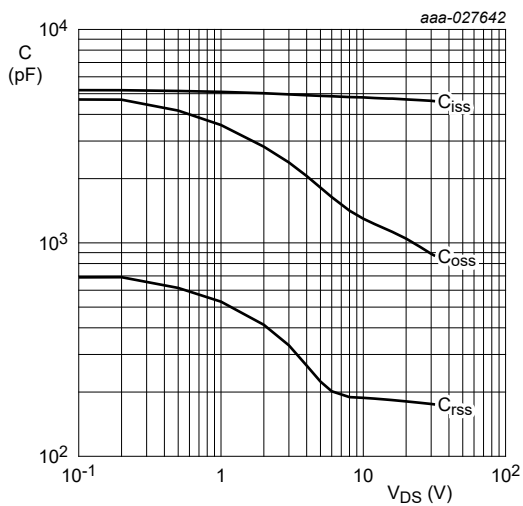
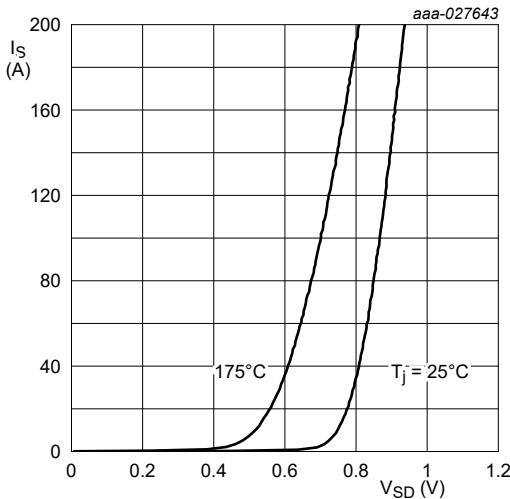


Fig. 14. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values



$V_{GS} = 0\text{ V}$

Fig. 15. Source-drain (diode forward) current as a function of source-drain (diode forward) voltage; typical values

11. Package outline

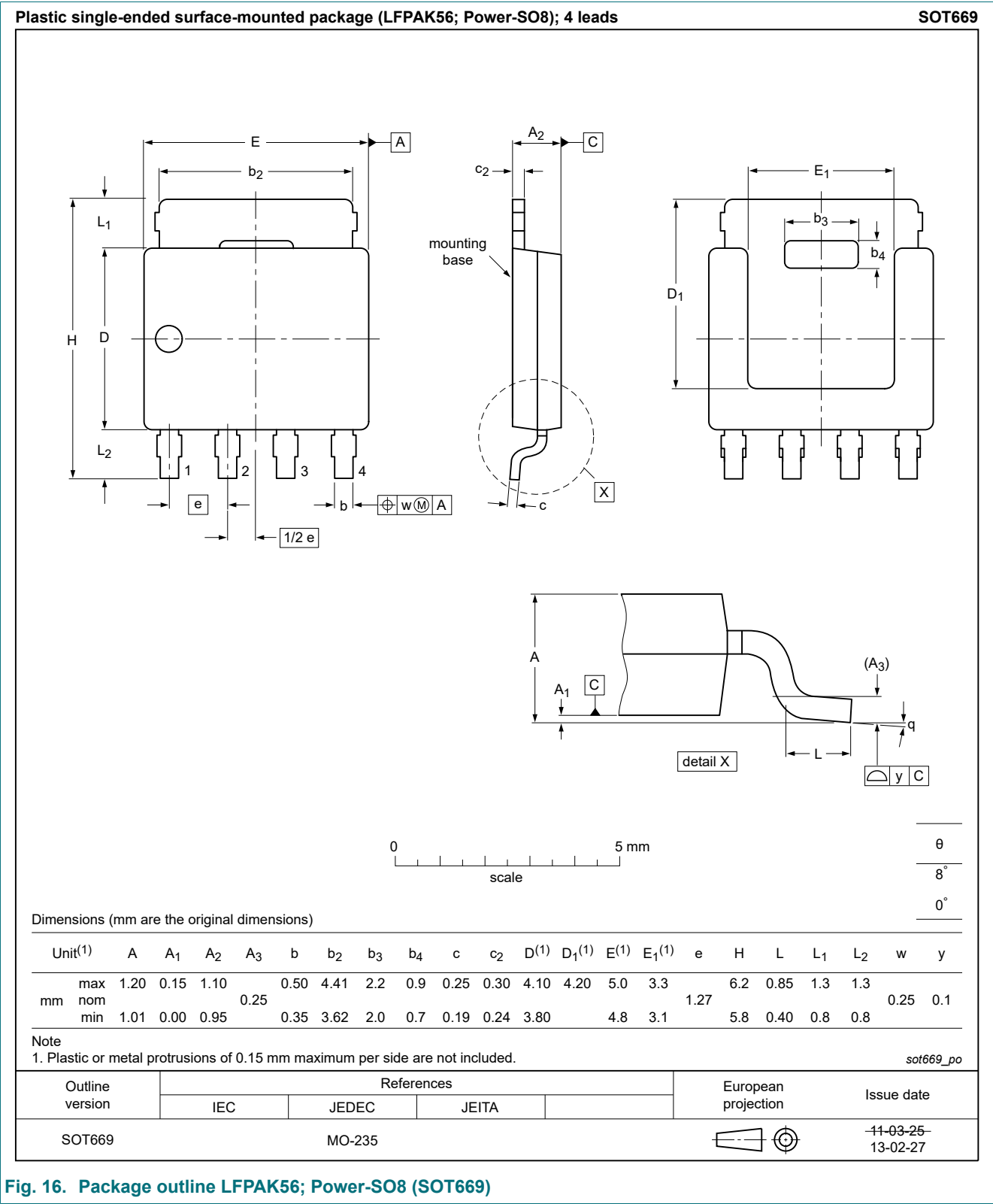


Fig. 16. Package outline LPAK56; Power-SO8 (SOT669)

12. Soldering

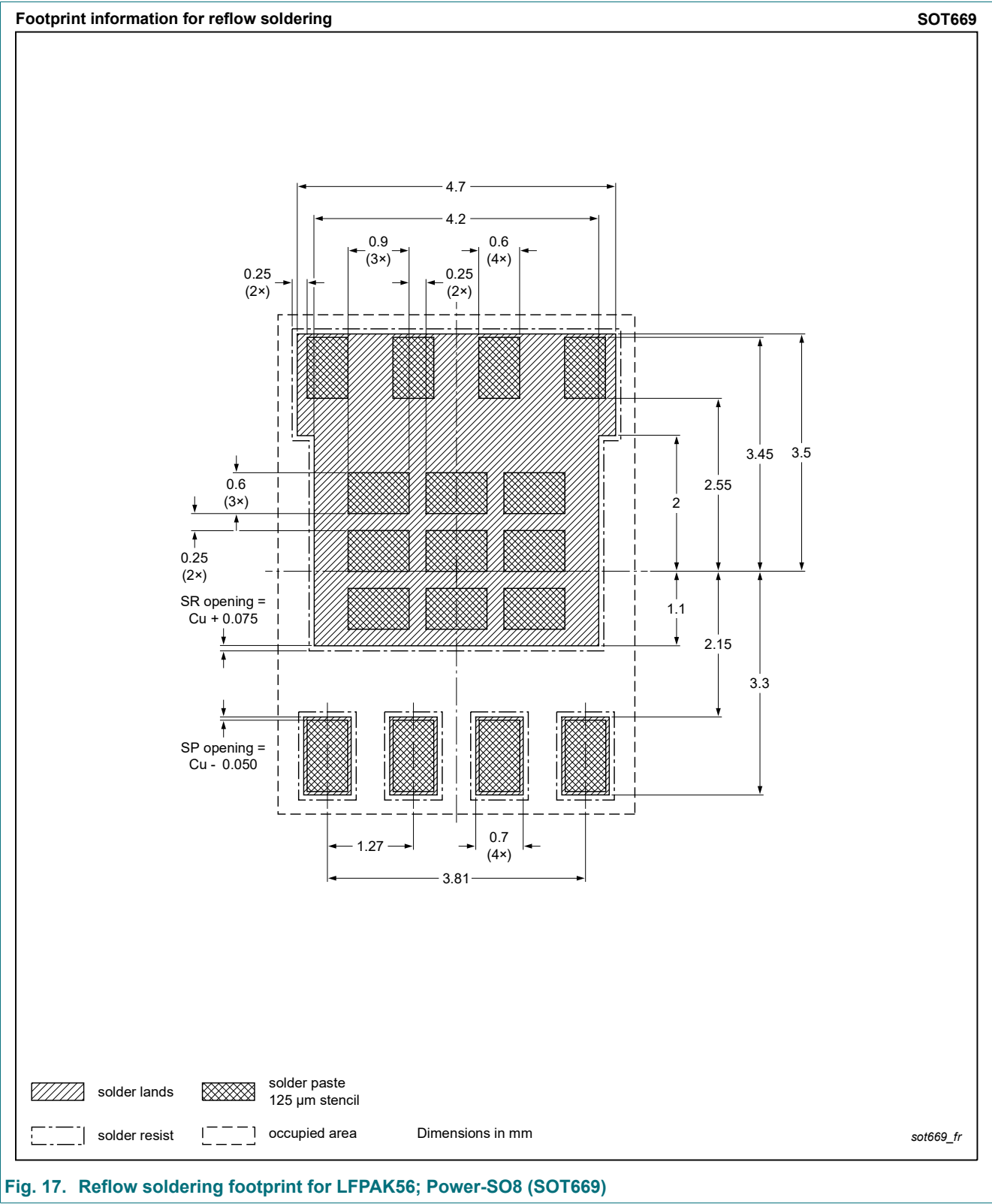


Fig. 17. Reflow soldering footprint for LPAK56; Power-SO8 (SOT669)

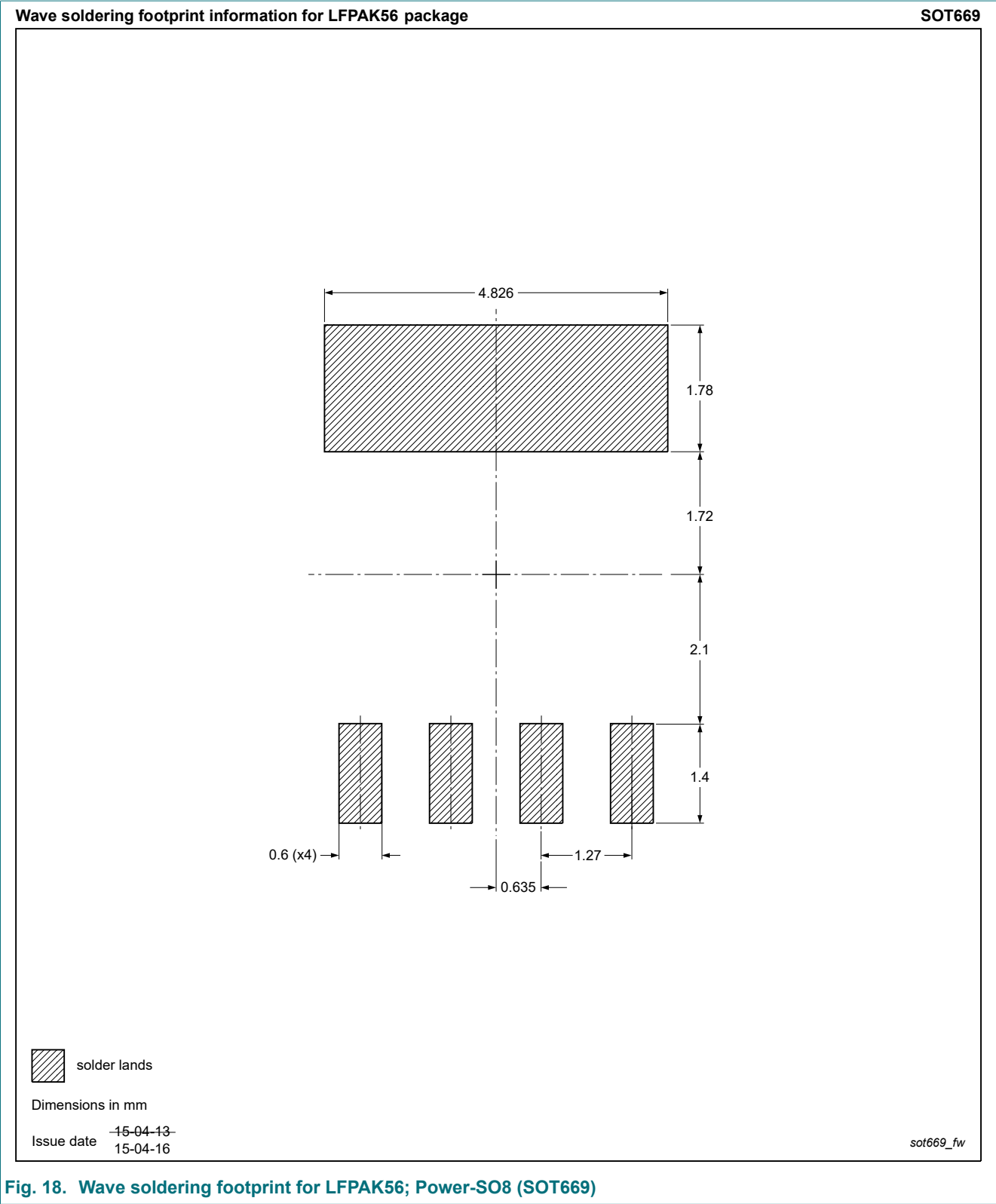


Fig. 18. Wave soldering footprint for LFPAK56; Power-SO8 (SOT669)

13. Legal information

Data sheet status

| Document status [1][2] | Product status [3] | Definition |
|--------------------------------|--------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
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